Amplifier Transistors

PNP Silicon

Features

• These are Pb-Free Devices*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Collector - Emitter Voltage	V _{CEO}	-45	Vdc	
Collector - Emitter Voltage	V _{CES}	-50	Vdc	
Emitter-Base Voltage	V _{EBO}	-5.0	Vdc	
Collector Current - Continuous	Ic	-800	mAdc	
Total Power Dissipation @ T _A = 25°C Derate above T _A = 25°C	P _D	625 5.0	mW mW/°C	
Total Power Dissipation @ T _A = 25°C Derate above T _A = 25°C	P _D	1.5 12	W mW/°C	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C	

THERMAL CHARACTERISTICS

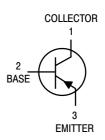
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	83.3	°C/W

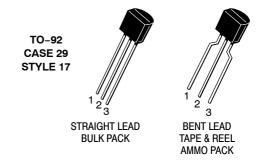
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



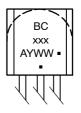
ON Semiconductor®

http://onsemi.com





MARKING DIAGRAM



BCxxx = Device Code

= Assembly Location

= Year WW = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering, marking, and shipping information in the package dimensions section on page 4 of this data sheet.

1

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•		•	•	
Collector – Emitter Breakdown Voltage $(I_C = -10 \text{ mA}, I_B = 0)$	V _{(BR)CEO}	-45	_	-	Vdc
Collector – Emitter Breakdown Voltage ($I_C = -100 \mu A, I_E = 0$)	V _{(BR)CES}	-50	-	-	Vdc
Emitter – Base Breakdown Voltage ($I_E = -10 \mu A, I_C = 0$)	V _{(BR)EBO}	-5.0	-	-	Vdc
Collector Cutoff Current (V _{CB} = -30 V, I _E = 0)	I _{CBO}	-	-	-100	nAdc
Collector Cutoff Current (V _{CE} = -45 V, V _{BE} = 0)	I _{CES}	-	-	-100	nAdc
Emitter Cutoff Current (V _{EB} = -4.0 V, I _C = 0)	I _{EBO}	-	-	-100	nAdc
ON CHARACTERISTICS					
DC Current Gain $ (I_C = -100 \text{ mA}, V_{CE} = -1.0 \text{ V}) $ BC327-1: BC327-2: BC327-4: $ (I_C = -300 \text{ mA}, V_{CE} = -1.0 \text{ V}) $	6 5	100 100 160 250 40	- - - -	630 250 400 630	-
Base–Emitter On Voltage (I _C = –300 mA, V _{CE} = –1.0 V)	V _{BE(on)}	_	_	-1.2	Vdc
Collector – Emitter Saturation Voltage (I _C = -500 mA, I _B = -50 mA)	V _{CE(sat)}	-	-	-0.7	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Output Capacitance (V _{CB} = -10 V, I _E = 0, f = 1.0 MHz)	C _{ob}	-	11	-	pF
Current – Gain – Bandwidth Product (I _C = –10 mA, V _{CE} = –5.0 V, f = 100 MHz)	f _T	-	260	_	MHz

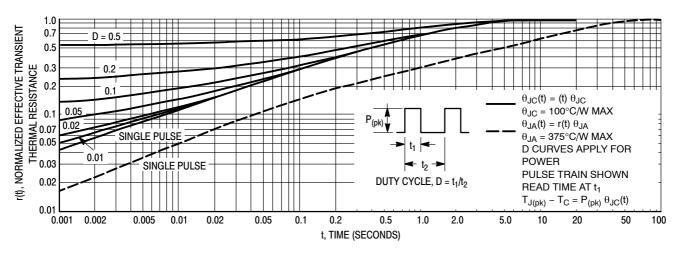


Figure 1. Thermal Response

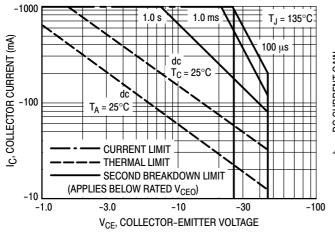


Figure 2. Active Region – Safe Operating Area

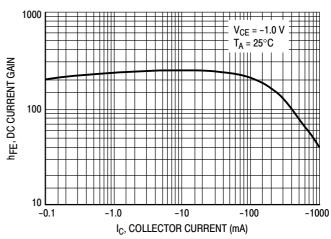


Figure 3. DC Current Gain

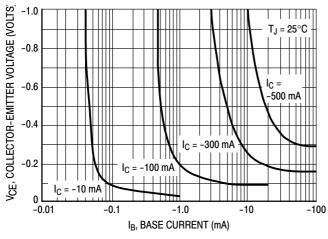


Figure 4. Saturation Region

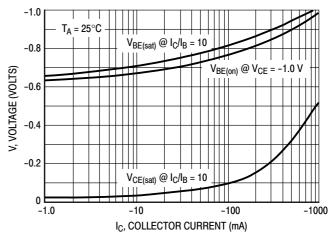


Figure 5. "On" Voltages

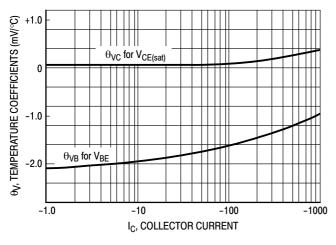


Figure 6. Temperature Coefficients

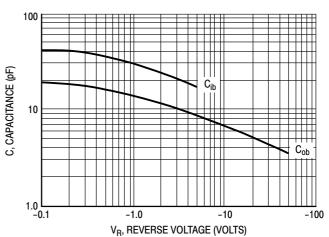


Figure 7. Capacitances

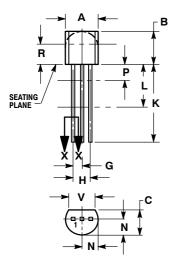
ORDERING INFORMATION

Device Order Number	Specific Device Marking	Package Type	Shipping [†]
BC327G	7	TO-92 Straight Lead (Pb-Free)	5000 Units / Bulk
BC327RL1G	327	TO-92 Bent Lead (Pb-Free)	2000 / Tape & Reel
BC327-025G	327	TO-92 Straight Lead (Pb-Free)	5000 Units / Bulk
BC327-25RL1G	7–25	TO-92 Bent Lead (Pb-Free)	2000 / Tape & Reel
BC327-25ZL1G	32725	TO-92 Bent Lead (Pb-Free)	2000 / Tape & Ammo Box
BC327-40ZL1G	7–40	TO-92 Bent Lead (Pb-Free)	2000 / Tape & Ammo Box

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AM**



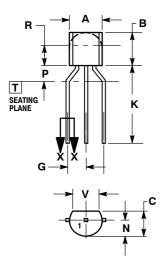
STRAIGHT LEAD **BULK PACK**



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM

	INC	HES	MALL I IN	IETERC
			MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.115		2.93	
V	0 135		3 43	



BENT LEAD TAPE & REEL AMMO PACK



NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
 CONTOUR OF PACKAGE BEYOND
- DIMENSION R IS UNCONTROLLED
- LEAD DIMENSION IS UNCONTROLLED IN PAND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS		
DIM	MIN	MAX	
Α	4.45	5.20	
В	4.32	5.33	
С	3.18	4.19	
D	0.40	0.54	
G	2.40	2.80	
J	0.39	0.50	
K	12.70		
N	2.04	2.66	
P	1.50	4.00	
R	2.93		
V	3.43		

STYLE 17:

PIN 1. COLLECTOR

2 BASE

EMITTER 3.

ON Semiconductor and un are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice on semiconductor and are registered readerlands of semiconductor Components industries, Ite (SCILLC) . Solitude services are inject to make changes without further holice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA

Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative